



DMNH4006SK3Q

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
40V	6mΩ @ V _{GS} = 10V	140A		

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- **Engine Management Systems**
- **Body Control Electronics**
- **DC-DC Converters**

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Features

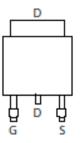
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low Qg Minimizes Switching Loss
- Low R_{DS(ON)} Minimizes On State Loss
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

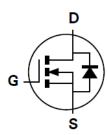
- . Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.315 grams (Approximate)



Top View



Pin Out Top View



Equivalent Circuit

Ordering Information (Note 5)

Part Number		Case	Packaging			
DMNH4006SK3Q-13		TO252 (DPAK)	2500/Tape & Reel			
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

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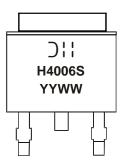
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Cili =Manufacturer's Marking H4006S = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016)WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current , V _{GS} = 10V (Note 7)	T _A = +25°C T _A = +70°C	ID	20 16	A
Continuous Drain Current , V_{GS} = 10V (Note 8) T _C = +25°C T _C = +100°C		I _D	140 100	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	IDM	200	А	
Maximum Continuous Body Diode Forward Current (Note 8)	Is	120	А	
Avalanche Current, L = 0.1mH (Note 9)	I _{AS}	64	А	
Avalanche Energy, L = 0.1mH (Note 9)	E _{AS}	208	mJ	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 6)		PD	2.2	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Р	68	°C/W	
Thermal Resistance, Sunction to Ambient (Note 6)	t<10s	$R_{ ext{ heta}JA}$	29	0/11	
Total Power Dissipation (Note 7)		PD	3.6	W	
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	D	42		
		$R_{ extsf{ heta}JA}$	21	°C/W	
Thermal Resistance, Junction to Case (Note 8)	$R_{ ext{ heta}JC}$	0.8			
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

	I					
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 10)						-
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current, T _J = +25°C	I _{DSS}	_		1	μA	$V_{DS} = 40V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 10)						
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	_	6	mΩ	$V_{GS} = 10V, I_D = 86A$
Diode Forward Voltage	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.0A$
DYNAMIC CHARACTERISTICS (Note 11)						
Input Capacitance	Ciss		2280	_	pF	
Output Capacitance	Coss		556	_	pF	− V _{DS} = 25V, V _{GS} = 0V, − f = 1MHz
Reverse Transfer Capacitance	Crss	—	282	_	pF	
Gate Resistance	Rg	_	1.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 6V)	Qg		32	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg		51	—	nC	V _{DS} = 32V. I _D = 86A
Gate-Source Charge	Q _{gs}		9.6	—	nC	$v_{DS} = 32v, I_D = 80A$
Gate-Drain Charge	Q _{gd}	_	20.4	—	nC	
Turn-On Delay Time	t _{D(ON)}		7.7	_	ns	
Turn-On Rise Time	t _R	_	9.3	_	ns	$V_{GS} = 10V, V_{DS} = 20V,$
Turn-Off Delay Time	t _{D(OFF)}		18	—	ns	$R_g = 3.5\Omega, I_D = 86A$
Turn-Off Fall Time	t _F		8.1	_	ns	
Body Diode Reverse Recovery Time	t _{RR}	_	32	-	ns	I _F = 50A, di/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}	_	28	_	nC	I _F = 50A, di/dt = 100A/µs

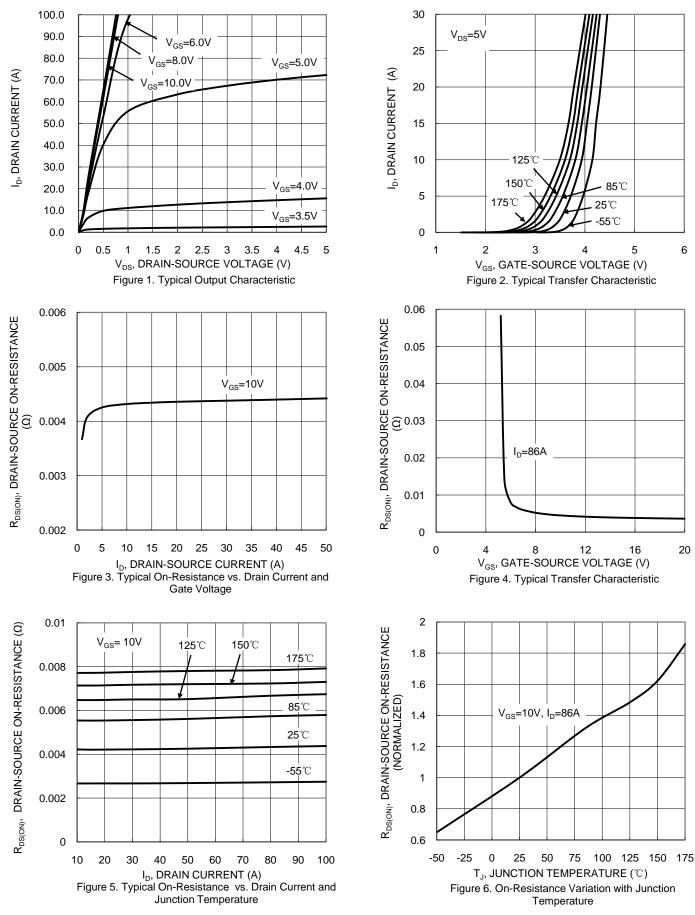
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. Thermal resistance from junction to soldering point (on the exposed drain pad).

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 10. Short duration pulse test used to minimize self-heating effect. 11. Guaranteed by design. Not subject to product testing.



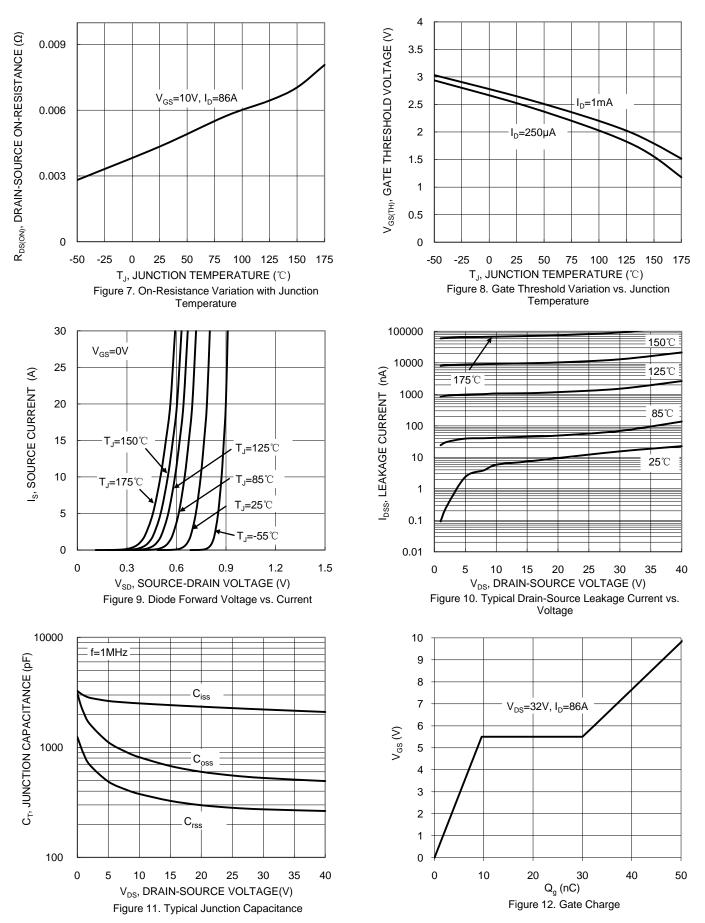
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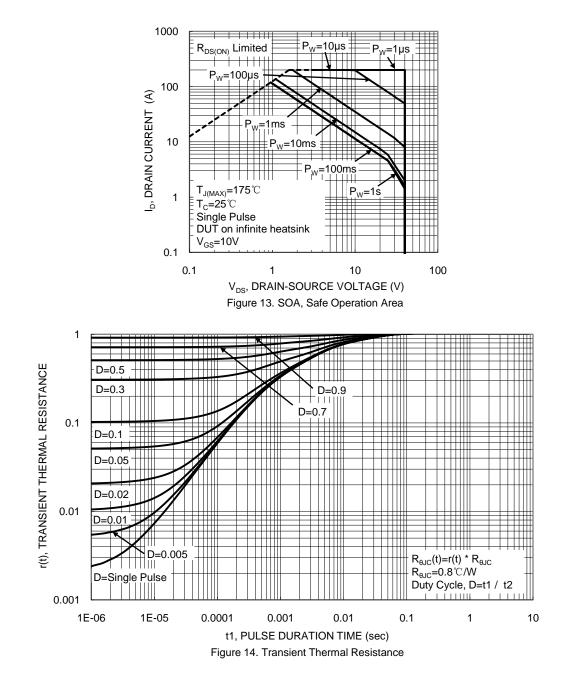
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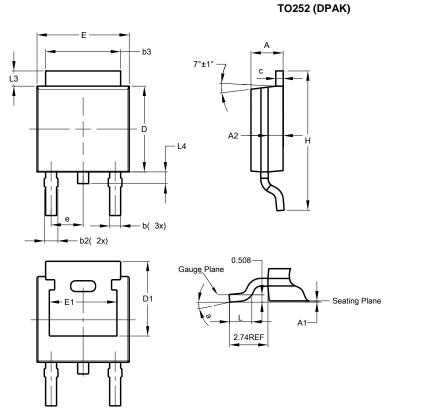






Package Outline Dimensions

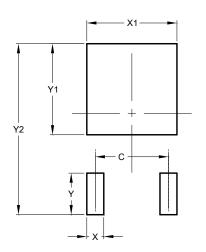
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21 -		-			
е	-					
Е	6.45	6.70	6.58			
E1	4.32 -		-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)

Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			



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